

■ Electro-optical Characteristics

($T_a = 25^\circ\text{C}$)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V_F	$I_F = 20\text{mA}$	-	1.2	1.4	V
	Peak forward voltage	V_{FM}	$I_{FM} = 0.5\text{A}$	-	3.0	4.0	V
	Reverse current	I_R	$V_R = 3\text{V}$	-	-	10	μA
Output	Collector dark current	I_{CEO}	$V_{CE} = 10\text{V}$	-	-	10^{-6}	A
Transfer characteristics	*3 Collector Current	GP2L01	$I_F = 10\text{mA}, V_{CE} = 2\text{V}$	3	-	-	mA
		GP2L01F		2.5	-	25	mA
	Response time	Rise time	$I_C = 10\text{mA}, V_{CE} = 2\text{V}, R_L = 100\Omega$ $d = 5\text{mm}$	-	80	400	μs
		Fall time		-	70	350	μs
	*4 Leak current	I_{LEAK}	$I_F = 10\text{mA}, V_{CE} = 2\text{V}$	-	-	100	μA

*3 Test method : A reflective object shall be an OMS test card (white) specified by Sharp, and be 5.0mm away from the sensor.

*4 Without reflective object

Fig. 1 Forward Current vs. Ambient Temperature

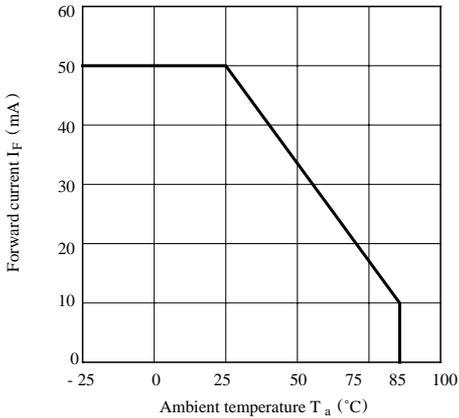


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

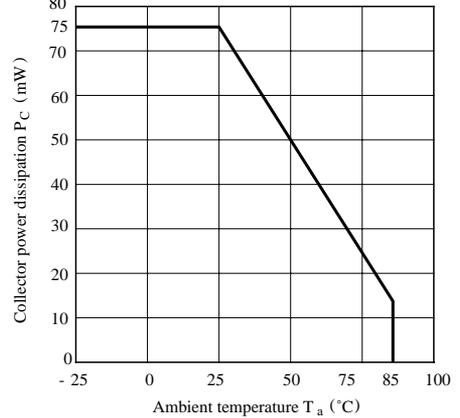


Fig. 3 Peak Forward Current vs. Duty Ratio

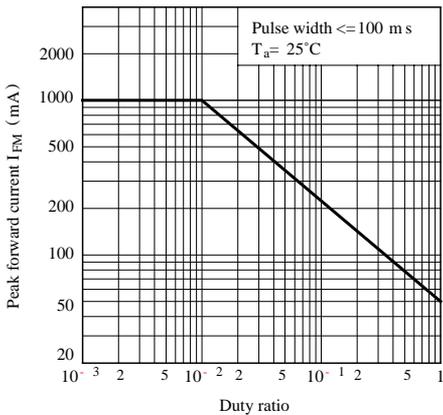


Fig. 4 Forward Current vs. Forward Voltage

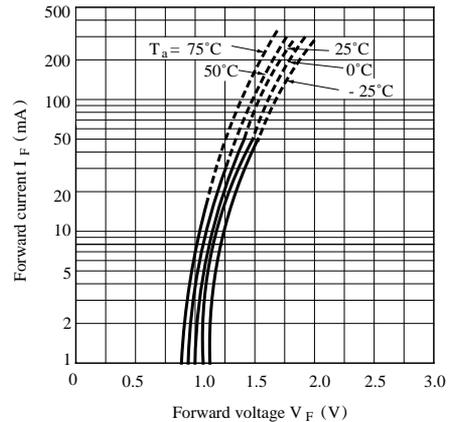


Fig. 5 Collector Current vs. Forward Current

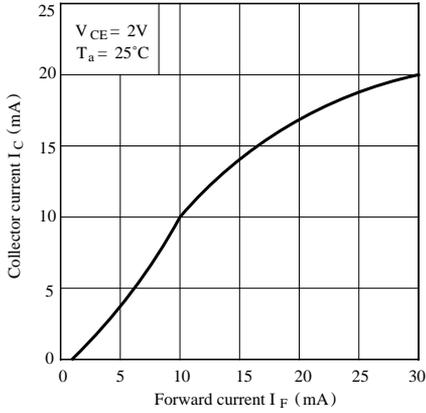


Fig. 6 Collector Current vs. Collector-emitter Voltage

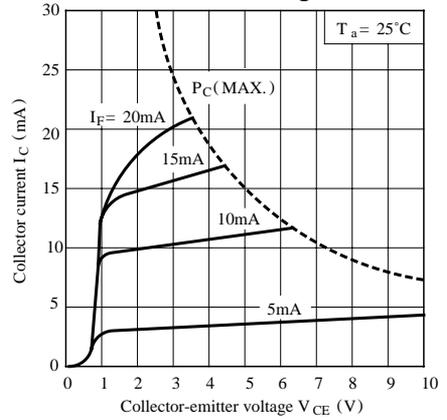


Fig. 7 Relative Collector Current vs. Ambient Temperature

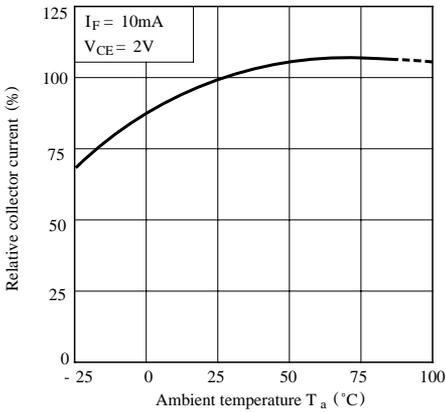


Fig. 8 Collector Dark Current vs. Ambient Temperature

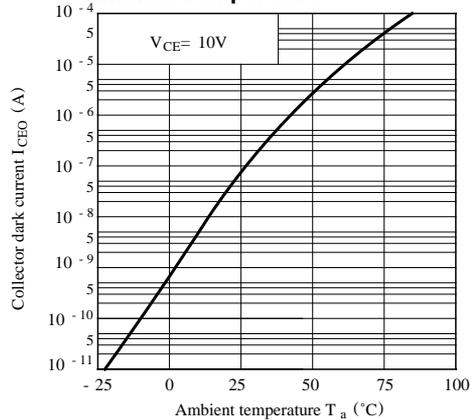
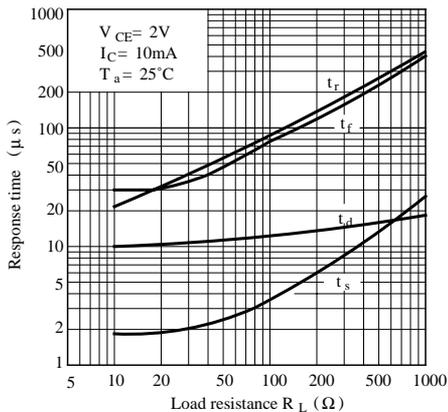


Fig. 9 Response Time vs. Load Resistance



Test Circuit for Response Time

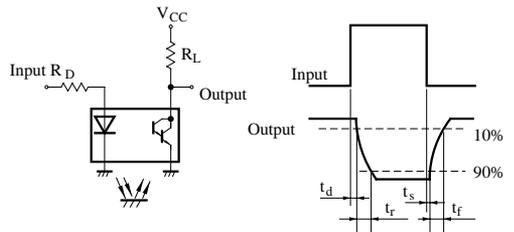


Fig.10 Frequency Response

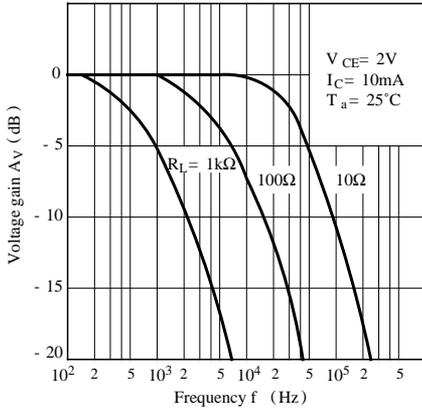


Fig.11 Relative Collector Current vs. Distance between GP2L01 (F) and Test Card

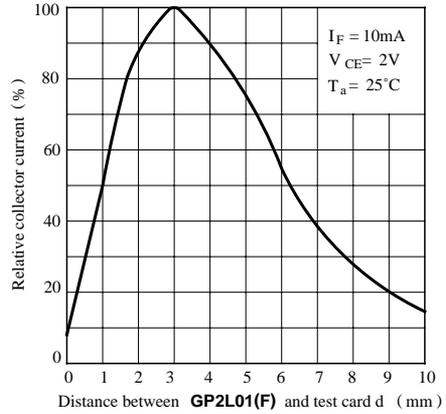
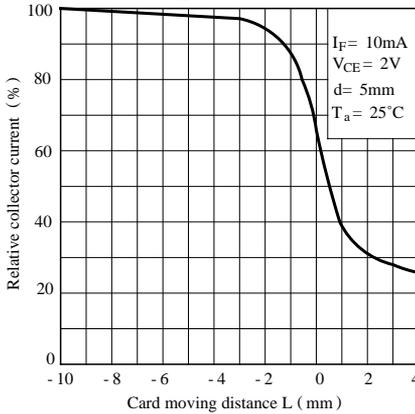


Fig.12 Relative Collector Current vs. Card Moving Distance



Distance Characteristic Test Conditions

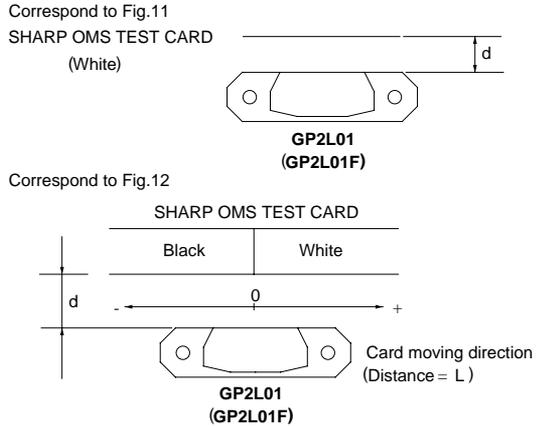
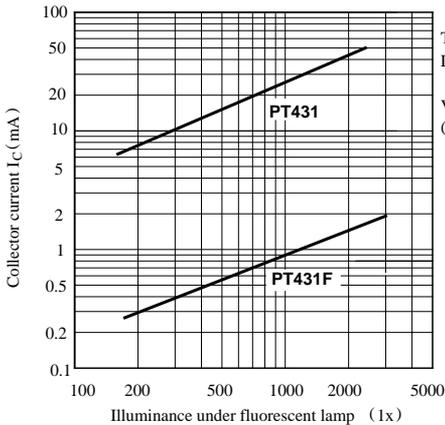


Fig.13 Collector Current vs. Illuminance (Reference)



Test condition
 Light source: White fluorescent lamp
 Sharp FLR-40SW/M
 $V_{CE} = 2V, T_a = 25^\circ C$
 (Note) Comparison between outputs of transparent resin molded type photo-transistor (PT431) and visible light cut-off type (PT431F)

- Please refer to the chapter “Precautions for Use”.